NSN 5961-01-249-1039

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-249-1039
Inclosure Material:
Metal
Overall Length:
0.565 inches
Overall Diameter:
1.650 inches
Internal Configuration:
Junction contact
Mounting Method:
Press fit
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
2.6 on-state voltage, dc
Current Rating Per Characteristic:
180.00 amperes on-state current, dc
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius junction
Special Features:
Internal junction configuration, pnpnp
Terminal Type And Quantity:
3 uninsulated wire lead w/terminal lug
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0